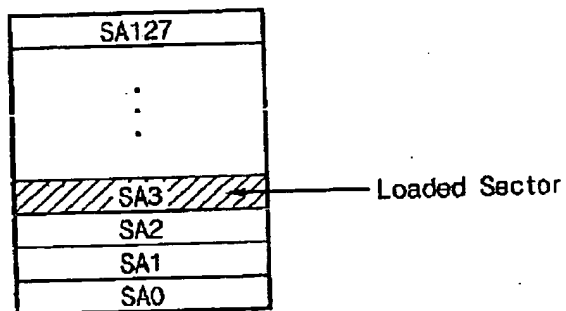


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Fig. 1

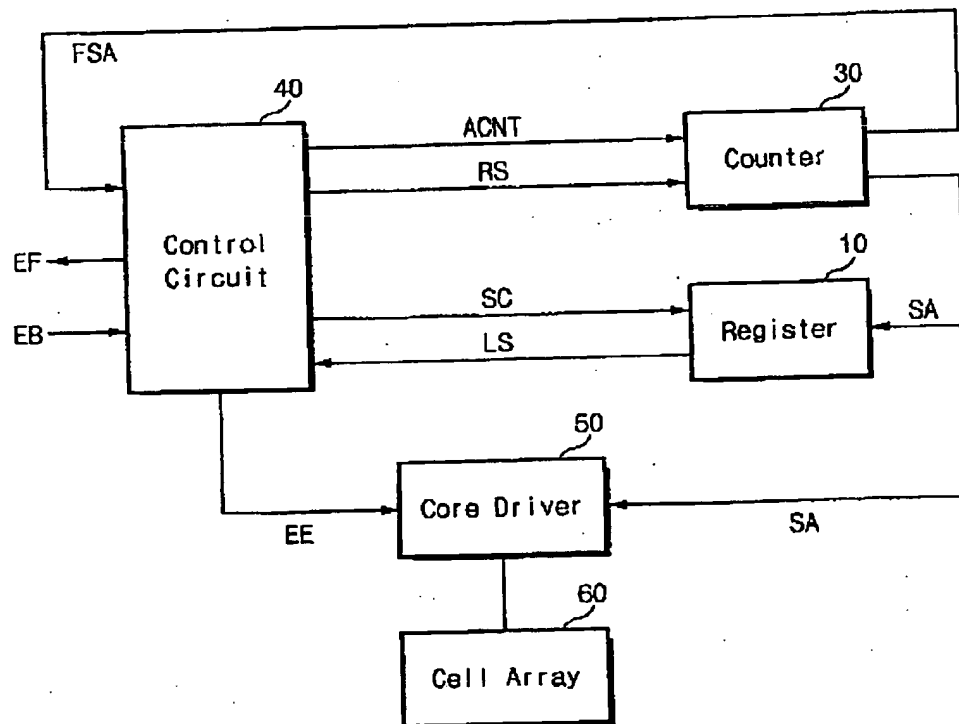
(PRIOR ART)



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Fig. 2

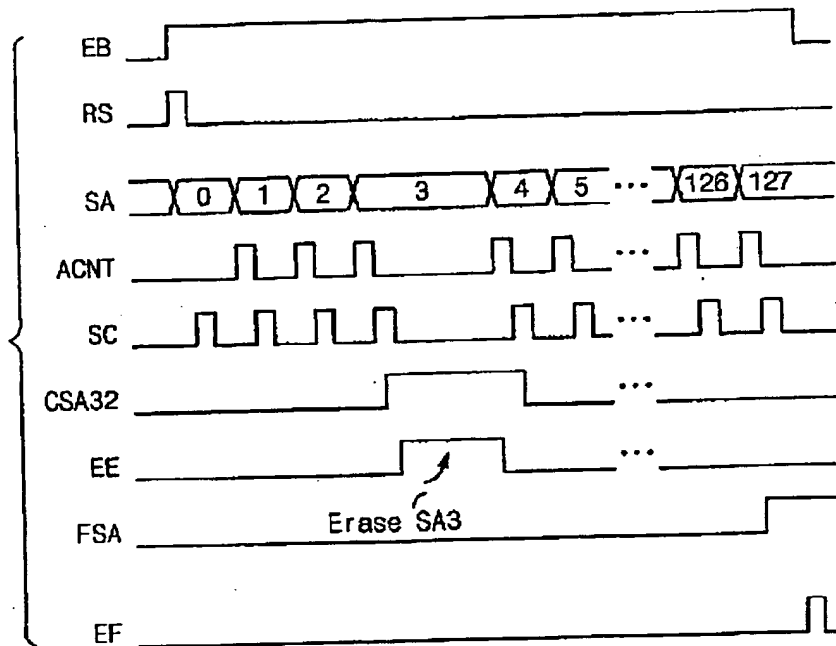
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Fig. 3

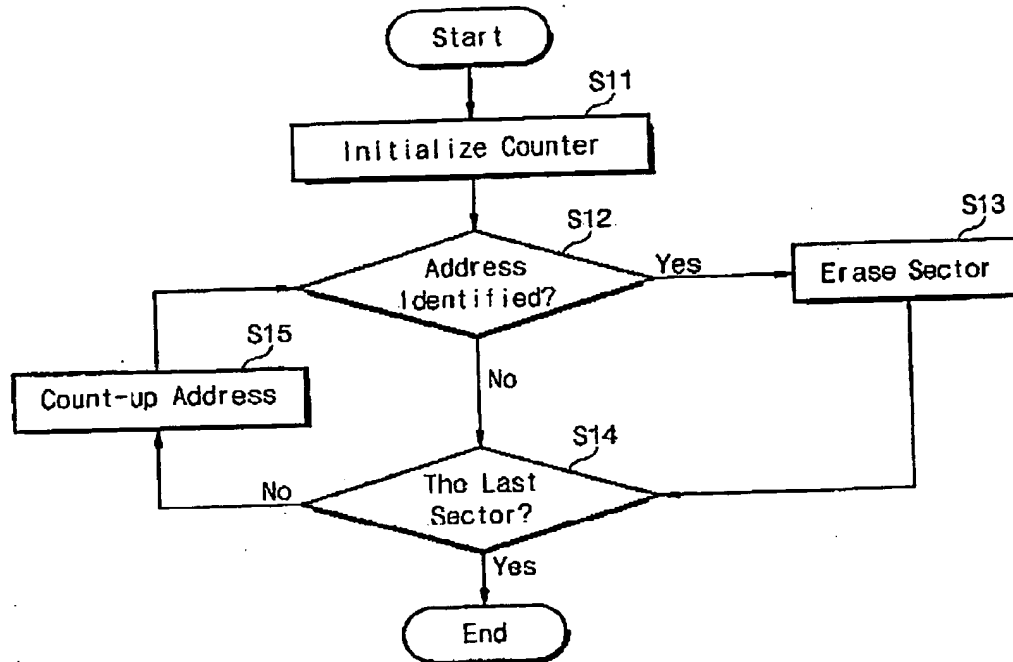
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Fig. 4

(PRIOR ART)



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Fig. 11

